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- Introduction and Corporate Overview

 Critical Customer Partnership Program
- SBE Power Ring Film Capacitor™
- Optimized DC Link Topology
- New: Prototype Bus Capabilities
- Summary
- Questions



SBE Corporate Overview



Established:1945 as Sprague Electric; SBE formed in 1985 with film cap lines purchased from SpragueLocations:Headquarters, Manufacturing and R&D Center: Barre, Vermont
Application Engineering and Sales: Colorado and China

Facilities:53,000 square feet new facility with capacity for over 100,000 VehiclesChina: engineering and assembly – 5,000 square feet

Distributors: Future Electronics – worldwide Richwood–China and Hong-Kong Flux Interconnect – Korea Jin Zon Enterprise- Taiwan Pulse Power & Measurement - UK

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Ownership: Privately Held Corporation

Markets:Transportation, Alternative Energy,
Medical/Laser, Military, UPS, HVDC, STATCOMKey Customers:TM4 - PEPS, ZF, Solectria Renewables,
Candela Laser, Vertiv, Caterpillar,
GE, Siemens, Dynapower
Danfoss, Hofer





Vermont Facility

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SBE Roadmap



State of the Art 53,000 square foot factory in Barre, Vermont

New Product: Integrated capacitor/bus



Critical Customer Partner Program

- SBE is overwhelmed with requests for highly customized cap/bus designs
- In December 2018 we implemented our Critical Customer Partner Program
 - Various membership levels available to guarantee engineering support and production capacity
 - Down payment required to lock in project schedule
 - Lead time to start new programs for non-partners is 8-12 weeks

The Power Ring Advantage

- Film is film to all capacitor vendors everyone has access to the same film suppliers
- SBE has targeted the annular <u>form factor</u> to provide the best possible performance
 - Significant investment in proprietary winding technology
 - Patent coverage for key technology aspects
 - Integration of polymer winding with copper terminals
 - Advanced design and simulation capabilities
 - Understand performance at the system integration level
- Industry second source Rogers Corp.



Key Technology Factors

- Large monolithic winding for lower cost
 - Better performance than a bank of smaller parts
- Short current path provides very low ESR
 - Low losses

- Large thermal cross section area provides efficient heat removal
 - Minimal hot spot temperature rise
 - Highest possible current rating for given capacitance
 - Best performance for ANY film



Key Technology Factors

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 Maximize A/μF so μF/kW is defined by control limit <u>not</u> capacitor current rating



SBE Next Generation Film Capacitor Solutions

Power Ring Film Capacitor[™] is a Building Block for Enabling Technology at the SYSTEM Level

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Pulse caps with excellent reliability and peak current rating

AC Filter – Oil free patented segmentation eliminates catastrophic failures



DC Link – Integrated cap/bus for high performance traction drive

DC Link – integrated cap/bus for increased power density in alternative energy and network power



Introduction to DC Link

- Traditional inverter design takes the approach of adding μF until the capacitor bank can handle current to achieve the required life
 - This is not effective in terms of power density, cost, or volume
- Working voltage and switching speed (efficiency) limited by the ESL of the DC link
 - Interconnection between DC link capacitor and switch module is limiting factor



SBE DC Link Technology

- Objective: Provide an optimized DC link such that customer can extract maximum value from investment in switch modules
- This is achieved as follows:

- Provide highest possible Ampere/ μ F rating such that capacitance is defined by control limit rather than capacitor life (minimize μ F/kW)
- Integrated cap/bus to provide the lowest possible inductance at switch module inputs



SBE DC Link Technology

- Packaging and integration of the capacitors is critical for best performance
 - Optimize terminal configuration for capacitor to improve magnetic flux cancellation
 - Integrate capacitor(s) directly onto the bus structure as "surface mount" devices
 - Eliminate redundant conductor layers
 - Improve connection geometry from cap/bus to switch module(s) = optimal <u>TOPOLOGY</u>



SBE DC Link Topology

Example: 777A104 Test Kit (3000uF at 1100V)



Enabling Ecosystem

- Next generation inverters must improve power density and efficiency
 - This requires an enabling "ecosystem" to support the semiconductor switches
 - Gate driver
 - Bus bar
 - DC link capacitor
 - Cooling

SBE integrated cap/bus topology forms the foundation



Enabling Ecosystem

- Advanced Silicon
 - Higher operating voltage
 - Faster switching
 - Massive paralleling of switch modules to achieve very high current
- Silicon Carbide
 - Higher operating voltage
 - Higher operating temperature
 - Very fast switching
 - Parallel modules needed to get to medium current



Enabling Ecosystem

- The enabling DC link requires the following ingredients
 - Optimized topology and bus structure
 - Very low commutation inductance
 - Paralleling of switch modules (balancing)
 - Very low capacitor losses
 - Higher capacitor working voltages
 - Increasing capacitor temperatures



Paralleling Modules

DC Link for Paralleling Infineon XHP[™] Modules

Add additional rows of 4x windings as needed for system mF value (e.g. weak grid)

Back-to-back parallel ring capacitors

SBE 700A241

Extend laminated bus over switch modules and make coaxial "through hole" connections to reduce ESL (< 10nH seen by modules)



Paralleling Modules

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Paralleling Modules

- Infineon double pulse testing demonstrates current balancing is better than 5% with 10x modules in parallel
- The use of two-sided cooling plate for modules complicates topology => multiple bus components needed
 - "C" bus connected to main cap/bus with multiple parallel coaxial contacts



Higher Working Voltage

- Example: HVDC and SVC applications
 - 2.8kV and up

- Customers are now looking to reduce all component losses
- Power density = capacitance density
 - Thinner film to manage capacitor volume
 - Lighter metallization to support higher operating stresses
 - SBE form factor can actually reduce ESR while taking this approach



Higher Working Voltage

The traditional "box cap"

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Improved "box cap" with lower losses using SBE rings

- Dissipation losses are the same
- Electrode losses are reduced by up to 3x

Array of ring capacitors / connected to bus plates with patented technology





Low ESL "crown terminal"

Higher Temperature



- SBE is exclusive supplier of PEN HV film for capacitor sizes compatible with Power Ring
- Excellent quality achieved with SBE's unique winding equipment
- Enables operation beyond 125C

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- Dielectric strength and self-healing comparable to polypropylene
- PEN HV windings can readily be utilized for existing DC link designs



New: Prototype Bus Capabilities

- The bus industry currently has prototype lead times ranging from 12 to 25 weeks
 - This does not support rapid customer validation of SBE cap/bus technology
- SBE will be implementing in-house prototype bus fabrication in Q2 2019 for critical customer partners
- We will continue to maintain strong relationship with industry leading bus vendors for production



Summary

- Lowest µF/kW rating
 - Smallest size and lowest cost
- SBE DC link is a key component of the enabling "ecosystem" for advanced Si and SiC applications
 - Critical for paralleling of modules
- Integrated cap/bus for low ESL
 - Allows for much greater switch utilization
- SBE is bringing prototype bus fabrication on line in Q2 2019
- Please stop by our booth (930) and discuss your application with the SBE team

